### TOSHIBA TRANSISTOR SILICON NPN TRIPLE DIFFUSED TYPE

# 2 S C 3 4 0 5

SWITCHING REGULATOR AND HIGH VOLTAGE SWITCHING APPLICATIONS

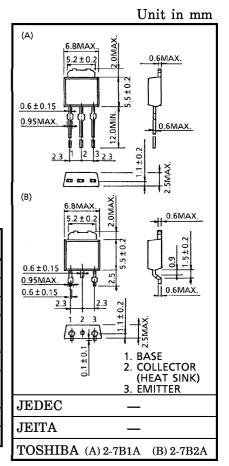
HIGH SPEED DC-DC CONVERTER APPLICATIONS

• Excellent Switching Times (I<sub>C</sub> = 0.3 A) :  $t_r = 1.0 \mu s$  (Max.),  $t_f = 1.0 \mu s$  (Max.)

• High Collector Breakdown Voltage :  $V_{CEO} = 800 \text{ V}$ 

## MAXIMUM RATINGS (Tc = 25°C)

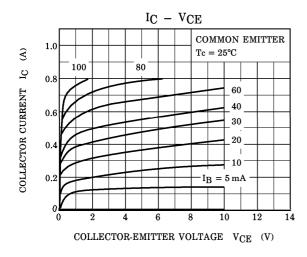
CHARACTE	SYMBOL	RATING	UNIT		
Collector-Base Voltage		$v_{\mathrm{CBO}}$	900	V	
Collector-Emitter Voltage		$V_{CEO}$	800	V	
Emitter-Base Voltage		$V_{ m EBO}$	8	V	
Collector Current	DC	$I_{\mathbf{C}}$	0.8	A	
	Pulse	ICP	1.5		
Base Current		$I_{\mathbf{B}}$	0.2	A	
Collector Power	$Ta = 25^{\circ}C$	Da	1.0	w	
Dissipation	$Tc = 25^{\circ}C$	PC	20		
Junction Temperature		$T_{j}$	150	°C	
Storage Temperature Range		$T_{ m stg}$	-55~150	°C	

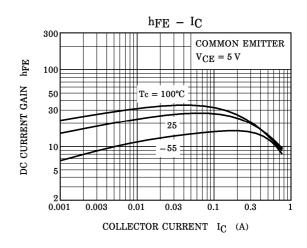


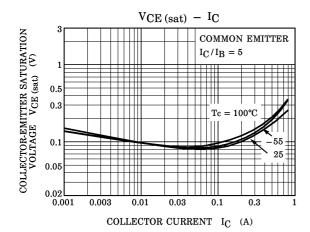
Weight: 0.36 g (Typ.)

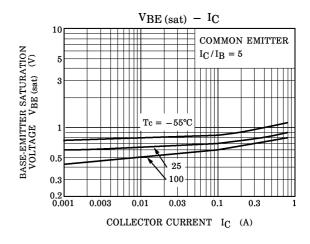
## ELECTRICAL CHARACTERISTICS (Tc = 25°C)

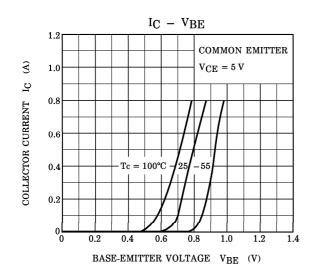
CHARAC	TERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off	Current	$I_{CBO}$	$V_{CB} = 800 \text{ V}, I_{E} = 0$	_	_	100	$\mu$ <b>A</b>
Emitter Cut-off	Current	$I_{EBO}$	$V_{EB} = 8 V, I_{C} = 0$	_	_	1	mA
Collector-Base B Voltage	reakdown	V (BR) CBO	$I_{\mathrm{C}}=1\mathrm{mA},~I_{\mathrm{E}}=0$	900	_	_	V
Collector-Emitte Voltage	r Breakdown	V (BR) CEO	$I_{\mathrm{C}}=10\mathrm{mA},~I_{\mathrm{B}}=0$	800	_	_	V
DC Current Gain		hFE (1)	$V_{CE} = 5 V$ , $I_{C} = 1 mA$	6		_	-
		h <sub>FE</sub> (2)	$V_{CE} = 5 V, I_{C} = 0.3 A$	10		_	
Collector-Emitter Saturation Voltage		V <sub>CE</sub> (sat)	$I_{\rm C} = 0.3~{\rm A},~I_{\rm B} = 0.06~{\rm A}$	_	_	0.5	V
Base-Emitter Saturation Voltage		V <sub>BE</sub> (sat)	$I_C = 0.3 \text{ A}, I_B = 0.06 \text{ A}$	_	_	1.2	V
Switching Time	Rise Time	t <sub>r</sub>	$I_{B1} \stackrel{IN-}{\longleftarrow} I_{B1} \stackrel{OUTPUT}{\longleftarrow} I_{B2} \stackrel{I}{\longleftarrow} \stackrel{I}{\longleftarrow} V_{CC} \stackrel{:}{\rightleftharpoons} 400 \text{ V}$	_	_	1.0	
	Storage Time	$t_{ ext{stg}}$		_	_	4.0	$\mu \mathrm{s}$
	Fall Time	$t_f$	$I_{B1} = -I_{B2} = 0.06 \text{ A},$ $DUTY \text{ CYCLE} \leq 1\%$		_	1.0	

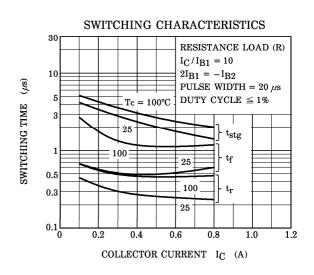


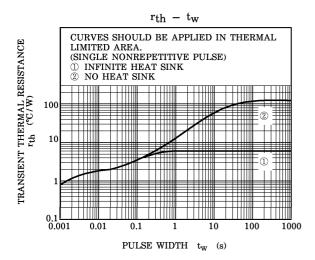


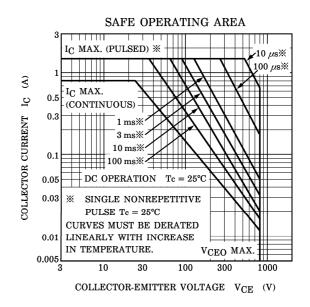












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